TOSHIBA Field Effect Transistor Silicon N-Channel MOS Type ( $\pi$ -MOSVI)

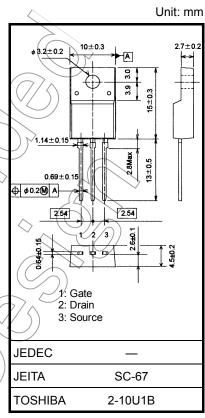
# 2SK3797

#### **Switching Regulator Applications**

- Low drain-source ON resistance:  $R_{DS (ON)} = 0.32 \Omega (typ.)$
- High forward transfer admittance: |Y<sub>fs</sub>| = 7.5 S (typ.)
- Low leakage current:  $I_{DSS} = 100 \mu A (V_{DS} = 600 V)$
- Enhancement model:  $V_{th}$  = 2.0 to 4.0 V ( $V_{DS}$  = 10 V,  $I_D$  = 1 mA)

## Absolute Maximum Ratings (Ta = 25°C)

Characteristic		Symbol	Rating	Unit
Drain-source voltage		$V_{DSS}$	600	$\bigvee$
Drain-gate voltage ( $R_{GS} = 20 \text{ k}\Omega$ )		$V_{DGR}$	600	V
Gate-source voltage		$V_{GSS}$	±30	> v
Drain current	DC (Note 1)	ΙD	13	
	Pulse (t = 1 ms) (Note 1)	I <sub>DP</sub>	52	A
Drain power dissipati	on (Tc = 25°C)	PD	50	<b>∠</b> ⟨w
Single pulse avalance	he energy (Note 2)	EAS	1033	mJ
Avalanche current		HAR	13 (	\ A
Repetitive avalanche	energy (Note 3)	(EAR)	5.0	Jωη
Channel temperature	. (	Tch	150	/_ce
Storage temperature	range	T <sub>stg</sub>	-55 to 150	⇒.c

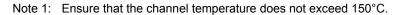


Weight: 1.7 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

### **Thermal Characteristics**

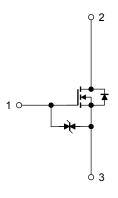
Characteristic	Symbol	Max	Unit
Thermal resistance, channel to case	R <sub>th (ch-c)</sub>	2.5	°C/W
Thermal resistance, channel to ambient	R <sub>th (ch-a)</sub>	62.5	°C/W



Note 2:  $V_{DD}$  = 90 V,  $T_{ch}$  = 25°C (initial), L = 10.7 mH,  $I_{AR}$  = 13 A,  $R_G$  = 25  $\Omega$ 

Note 3: Repetitive rating: pulse width limited by maximum channel temperature

This transistor is an electrostatic-sensitive device. Handle with care.

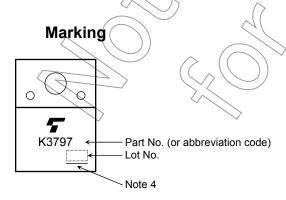


### **Electrical Characteristics (Ta = 25°C)**

Cha	racteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage cui	rrent	I <sub>GSS</sub>	$V_{GS} = \pm 25 \text{ V}, V_{DS} = 0 \text{ V}$	_	_	±10	μА
Gate-source brea	akdown voltage	V (BR) GSS	$I_G = \pm 10 \ \mu A, \ V_{DS} = 0 \ V$	±30	_	_	V
Drain cutoff curre	ent	I <sub>DSS</sub>	V <sub>DS</sub> = 600 V, V <sub>GS</sub> = 0 V	/		100	μА
Drain-source bre	akdown voltage	V (BR) DSS	I <sub>D</sub> = 10 mA, V <sub>GS</sub> = 0 V	600			٧
Gate threshold v	oltage	V <sub>th</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 1 mA	2.0	)	4.0	V
Drain-source ON	resistance	R <sub>DS</sub> (ON)	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 6.5 A		0.32	0.43	Ω
Forward transfer	admittance	Y <sub>fs</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 7.0 A	2.)	7.5		S
Input capacitance	е	C <sub>iss</sub>			3100		
Reverse transfer capacitance		C <sub>rss</sub>	V <sub>DS</sub> = 25 V, V <sub>GS</sub> = 0 V, f = 1 MHz	· —	20	_	pF
Output capacitance		C <sub>oss</sub>		_	270		
Switching time	Rise time	t <sub>r</sub>	10 V ID=6.5 A VOUT	- (	60		
	Turn-on time	t <sub>on</sub>	0 V R <sub>L</sub> = 30Ω		110	) —	ns
	Fall time	t <sub>f</sub>	V <sub>DD</sub> ≈ 200 V	//(	> 50		110
	Turn-off time	t <sub>off</sub>	Duty ≤ 1%, t <sub>W</sub> = 10 μs		215	_	
Total gate charge	e	Qg		) —	62	_	
Gate-source cha	rge	Q <sub>gs</sub>	$V_{DD} \simeq 400 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 13 \text{ A}$	_	40	_	nC
Gate-drain charge Q <sub>g</sub>		Qgd		_	22	_	

## Source-Drain Ratings and Characteristics (Ta = 25°C)

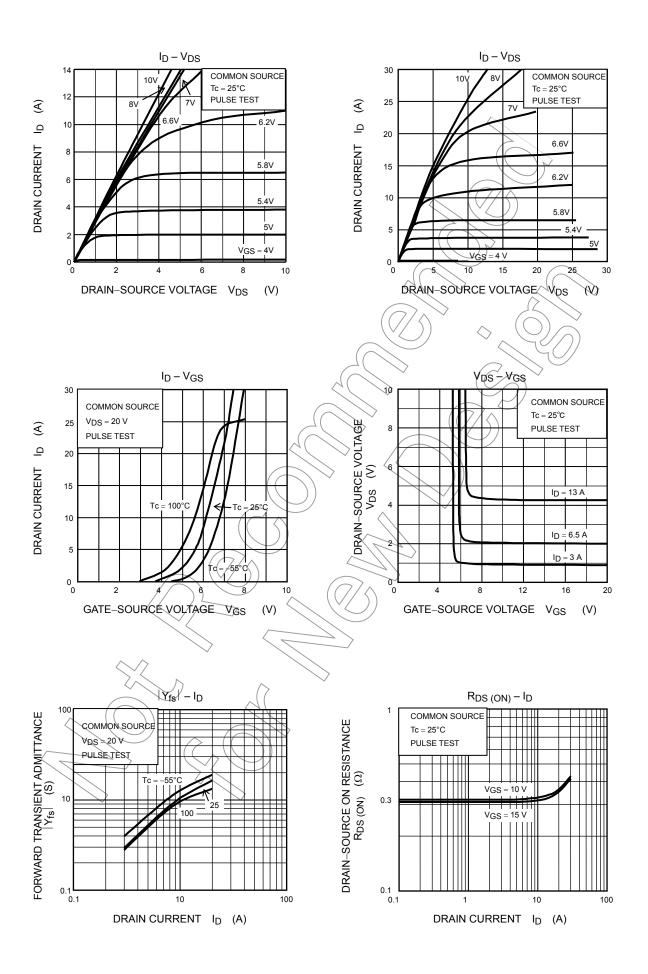
Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Continuous drain reverse current (Note 1)	)) I <sub>DR</sub>		_	_	13	Α
Pulse drain reverse current (Note 1)	IDRR		_	_	52	Α
Forward voltage (diode)	V <sub>DSF</sub>	I <sub>DR</sub> = 13 A, V <sub>GS</sub> = 0 V	_	_	-1.7	V
Reverse recovery time	tri	I <sub>DR</sub> = 13 A, V <sub>GS</sub> = 0 V,	_	1050		ns
Reverse recovery charge	Q <sub>rr</sub>	dI <sub>DR</sub> /dt = 100 A/μs	_	15		μС



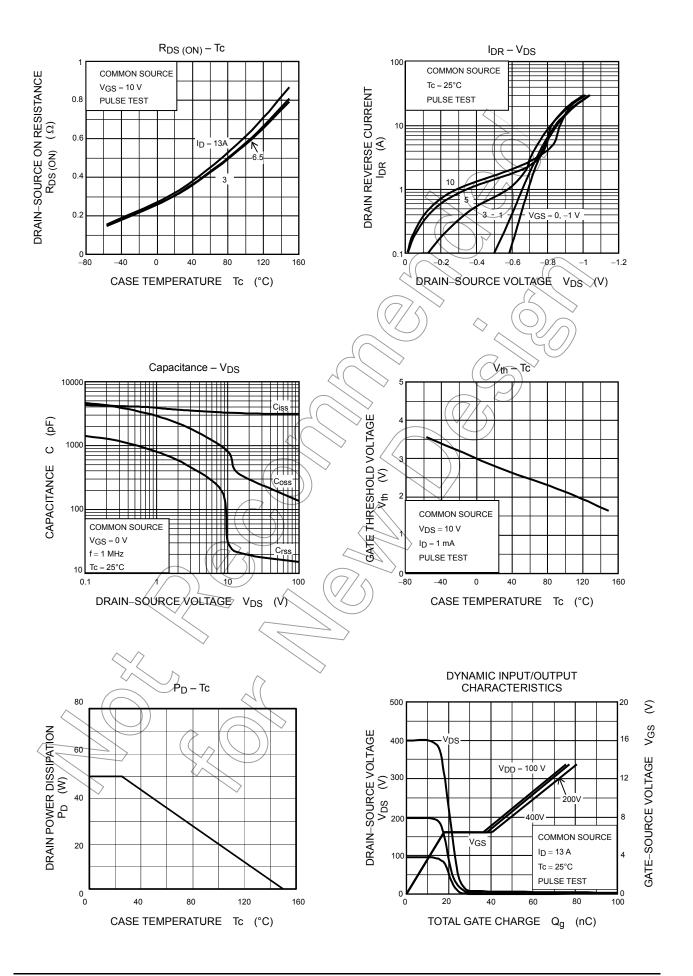
Note 4: A line under a Lot No. identifies the indication of product Labels.

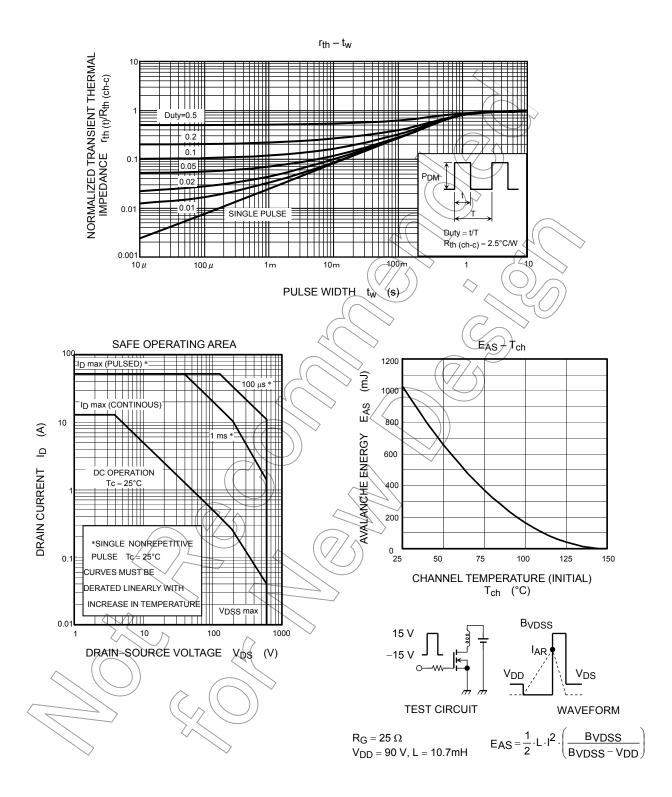
Not underlined: [[Pb]]/INCLUDES > MCV Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

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